

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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N-Channel Power MOSFET

600V, 38A, $99m\Omega$

FEATURES

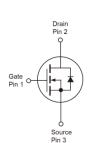
- Super-Junction technology
- High performance, small R_{DS(ON)}*Q_g figure of merit (FOM)
- High ruggedness performance
- 100% UIS and Rg tested
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS			
PARAMETER	VALUE UN		
V_{DS}	600	V	
R _{DS(on)} (max)	99	mΩ	
Q_g	62	nC	

APPLICATIONS

- PFC stage
- Server/Telecom Power
- Charging Station
- Inverter
- Power Supply





ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	600	V
Gate-Source Voltage		V _{GS}	±30	V
Continuous Drain Current (Note 1)	T _C = 25°C		38	Α
	$T_C = 100$ °C	I _D	24	Α
Pulsed Drain Current (Note 2)		I _{DM}	114	А
Total Power Dissipation @ $T_C = 25^{\circ}C$		P _D	329	W
Single Pulse Avalanche Energy (Note	3)	E _{AS}	784	mJ
Single Pulse Avalanche Current (Note	93)	I _{AS}	5.6	А
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	0.38	°C/W	
Junction to Ambient Thermal Resistance	R _{OJA}	42	°C/W	

Thermal Performance Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	600			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance (Note 4)	$V_{GS} = 10V, I_D = 11.7A$	R _{DS(on)}		86	99	mΩ
Dynamic (Note 5)		<u> </u>		•		•
Total Gate Charge		Qg		62		
Gate-Source Charge	$V_{DS} = 480V, I_D = 35A,$ $V_{GS} = 10V$	Q_{gs}		17		nC
Gate-Drain Charge		Q_{gd}		25		
Input Capacitance		C _{iss}		2587		
Output Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$ f = 1.0MHz	C _{oss}		123		pF
Reverse Transfer Capacitance	1 = 1.0IVIM2	C _{rss}		20		
Gate Resistance	f = 1.0MHz	R_{g}		3.3	6.6	Ω
Switching (Note 6)						
Turn-On Delay Time		t _{d(on)}		18		
Turn-On Rise Time	$V_{DD} = 300V,$	t _r		24		
Turn-Off Delay Time	$R_{GEN} = 5\Omega,$ $I_D = 17.5A, V_{GS} = 10V,$	t _{d(off)}		87		ns
Turn-Off Fall Time	10 - 17.5A, VGS - 10V,	t _f		25		
Source-Drain Diode						
Body-Diode Continuous Forward Cur	rrent	Is			38	Α
Body-Diode Pulsed Current		I _{SM}			114	Α
Forward Voltage (Note 4)	$I_S = 35A, V_{GS} = 0V$	V_{SD}			1.4	V
Reverse Recovery Time	I _S = 17.5A	t _{rr}		342		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q_{rr}		5.3		μC

Notes:

- 1. Current limited by package.
- 2. Pulse width limited by the maximum junction temperature.
- 3. L = 50mH, $I_{AS} = 5.6A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 4. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%.
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.

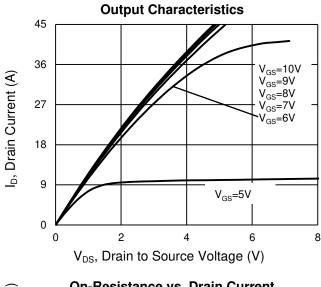
ORDERING INFORMATION

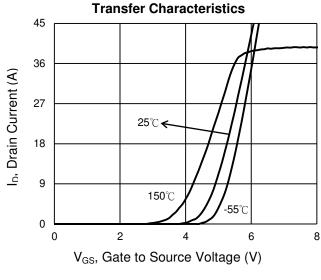
PART NO.	PACKAGE	PACKING
TSM60NB099PW C1G	TO-247	25pcs / Tube

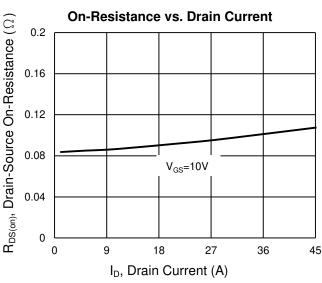


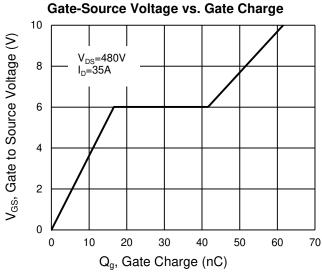
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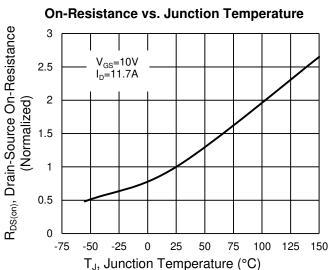
 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

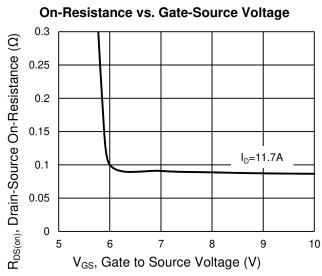












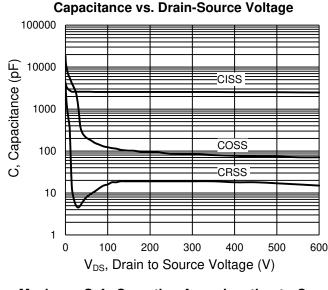
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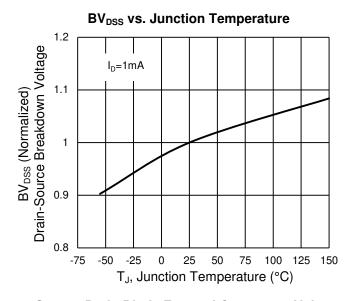
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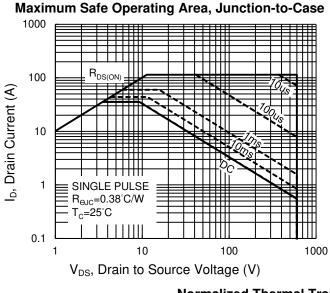


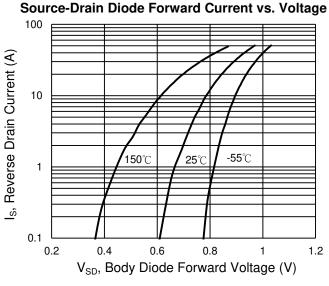
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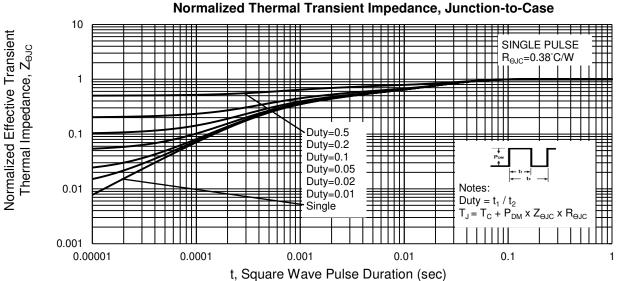
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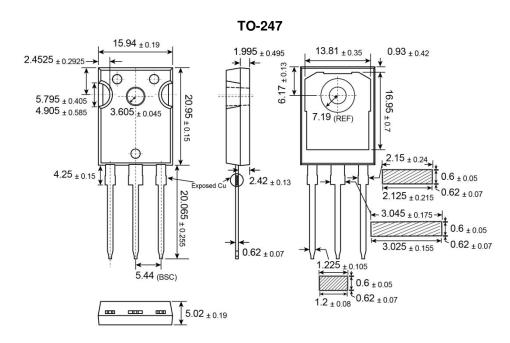








PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



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MARKING DIAGRAM



G = Halogen Free

Y = Year Code

WW = Week Code $(01 \sim 52)$

F = Factory Code



Taiwan Semiconductor

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